

IGBT MODULE (U series)

600V / 100A

■ Features

- Low $V_{CE(sat)}$
- Compact Package
- P.C. Board Mount Module



■ Applications

- Inverter for Motoe Drive
- AC and DC Servo Drive Amplifier
- Uninterruptible Power Supply

■ Maximum ratings and characteristics

● Absolute maximum ratings ($T_c=25^{\circ}\text{C}$ unless otherwise specified)

Item	Symbol	Condition	Rating	Unit
Collector-Emitter voltage	V_{CES}		600	V
Gate-Emitter voltage	V_{GES}		± 20	V
Collector current	I_c	Continuous	100	A
	I_{cP}	1ms	200	
	$-I_c$		100	
	$-I_c$ pulse		200	
Collector power dissipation	P_c	1 device	380	W
Operating junction temperature	T_j		+150	$^{\circ}\text{C}$
Storage temperature	T_{stg}		-40 to +125	$^{\circ}\text{C}$
Isolation voltage	V_{iso}	AC : 1 minute	AC 2500	V
			AC 2500	V
Mounting screw torque			3.5 *1	N·m

*1 Recommendable value : 2.5 to 3.5 N·m (M5)

*2 All terminals should be connected together when isolation test will be done.

*3 Two thermistor terminals should be connected together, each other terminals should be connected together and shorted to base plate when isolation test will be done.

● Electrical characteristics (Tj=25°C unless otherwise specified)

Item	Symbol	Condition	Characteristics			Unit
			Min.	Typ.	Max.	
Inverter	Zero gate voltage collector current	ICES	VCE=600V, VGE=0V		1.0	mA
	Gate-Emitter leakage current	IGES	VCE=0V, VGE=±20V		200	nA
	Gate-Emitter threshold voltage	VGE(th)	VCE=20V, IC=100mA		6.2	V
	Collector-Emitter saturation voltage	VCE(sat) (terminal)	VGE=15V	Tj=25°C	2.20	V
			IC=100A	Tj=125°C	2.35	
		VCE(sat) (chip)		Tj=25°C	1.85	
				Tj=125°C	2.00	
	Input capacitance	Cies	VGE=0V, VCE=10V, f=1MHz		8.4	nF
	Turn-on time	ton	VCC=300V		0.40	µs
		tr	IC=100A		0.22	
		tr(i)	VGE=±15V		0.16	
	Turn-off time	toff	RG= 33 Ω		0.48	µs
		tf			0.07	
	Forward on voltage	VF (terminal)	VGE= 0 V	Tj=25°C	1.95	V
			IF=100A	Tj=125°C	2.00	
		VF (chip)		Tj=25°C	1.60	
				Tj=125°C	1.65	
	Reverse recovery time	trr	IF=100A		0.35	µs
	Lead resistance, terminal-chip *	R lead			3.4	mΩ
Thermistor	Resistance	R	T=25°C		5000	Ω
			T=100°C		495	
	B value	B	T=25/50°C		3305	K

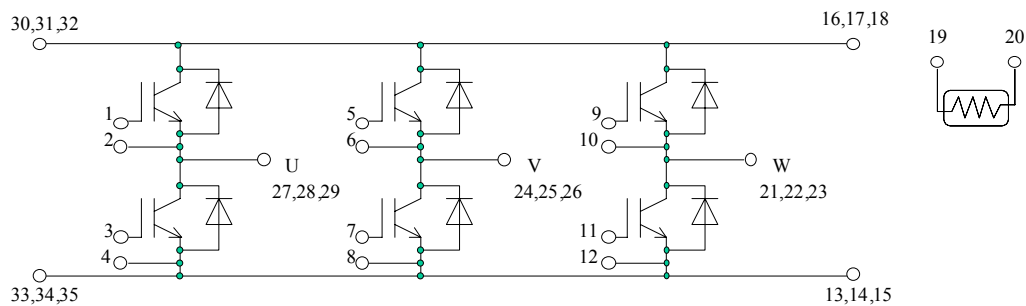
* Biggest internal terminal resistance among arm.

● Thermal resistance Characteristics

Item	Symbol	Condition	Characteristics			Unit
			Min.	Typ.	Max.	
Thermal resistance (1 device)	Rth(j-c)	IGBT	-	-	0.33	°C/W
		FWD	-	-	0.66	
Contact thermal resistance *	Rth(c-f)	With thermal compound	-	0.05	-	

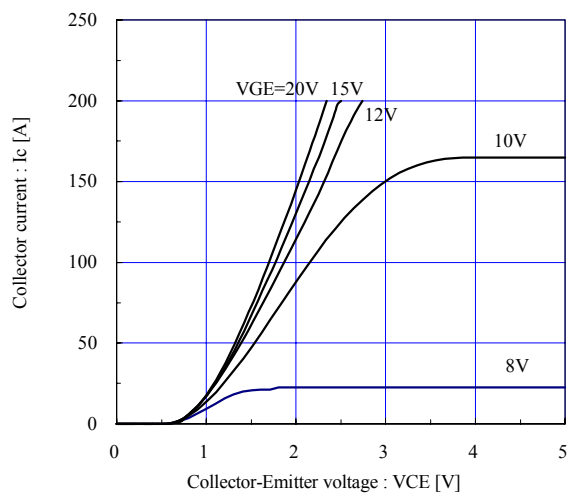
* This is the value which is defined mounting on the additional cooling fin with thermal compound

■ Equivalent Circuit Schematic

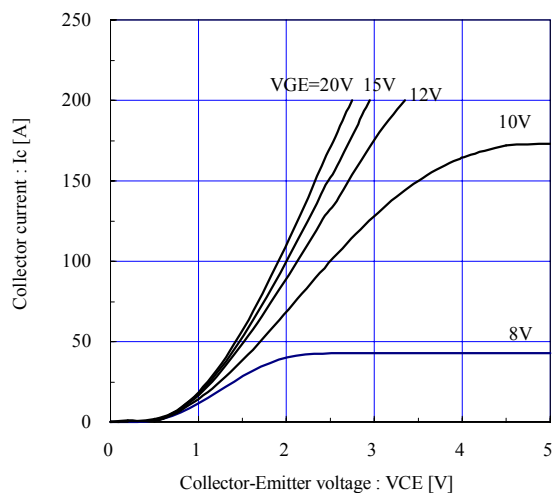


■ Characteristics (Representative)

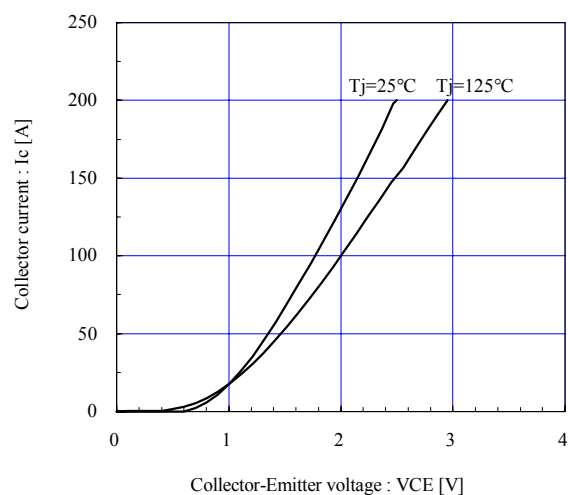
Collector current vs. Collector-Emitter voltage (typ.)

 $T_j = 25^\circ\text{C}$ / chip

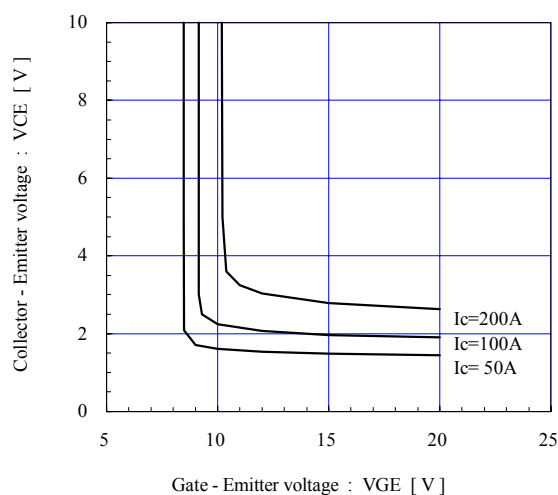
Collector current vs. Collector-Emitter voltage (typ.)

 $T_j = 125^\circ\text{C}$ / chip

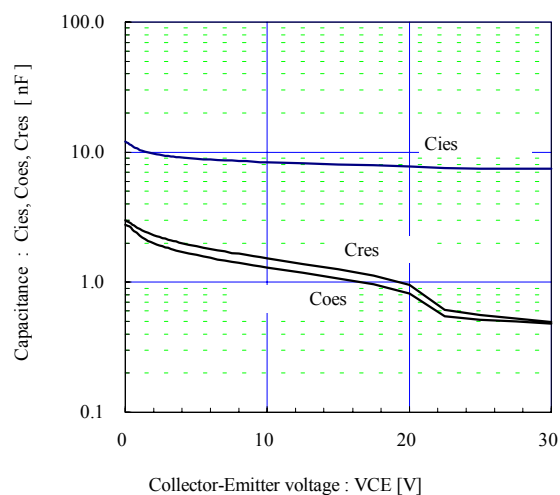
Collector current vs. Collector-Emitter voltage (typ.)

 $V_{GE} = 15\text{V}$ / chip

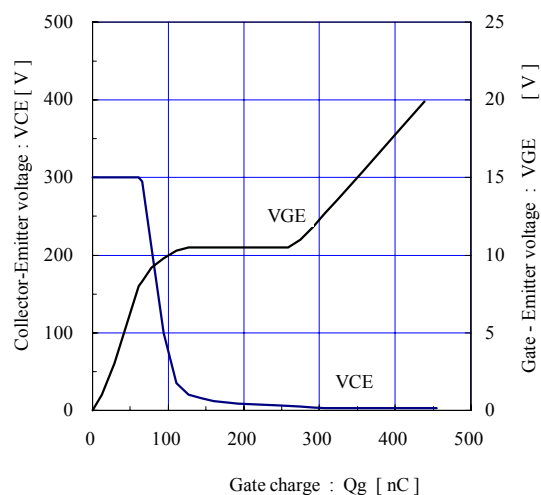
Collector-Emitter voltage vs. Gate-Emitter voltage (typ.)

 $T_j = 25^\circ\text{C}$ / chip

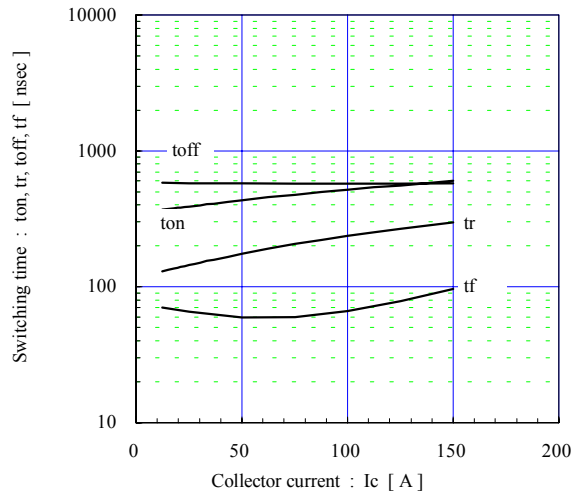
Capacitance vs. Collector-Emitter voltage (typ.)

 $V_{GE} = 0\text{V}$, $f = 1\text{MHz}$, $T_j = 25^\circ\text{C}$ 

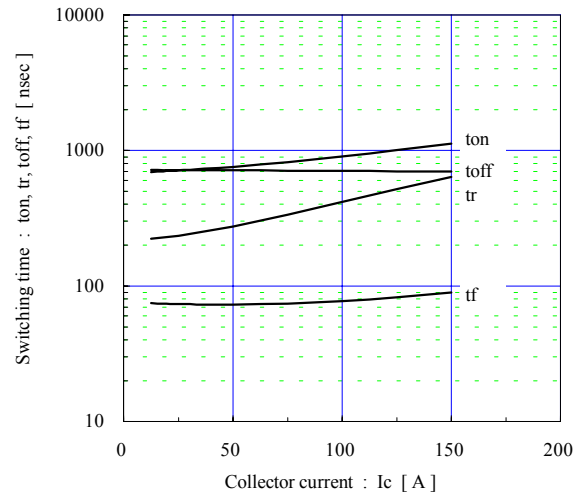
Dynamic Gate charge (typ.)

 $V_{cc} = 300\text{V}$, $I_c = 100\text{A}$, $T_j = 25^\circ\text{C}$ 

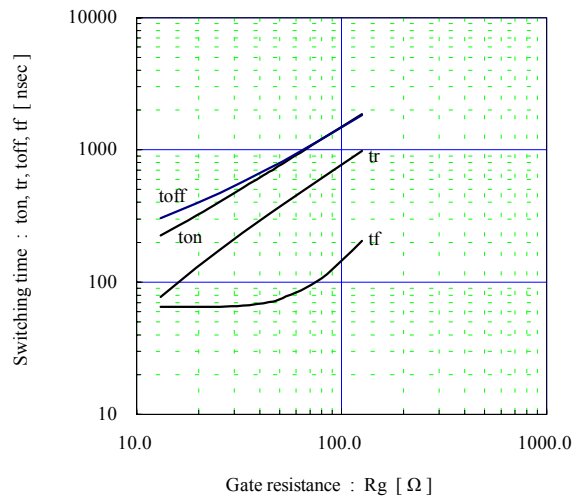
Switching time vs. Collector current (typ.)
 $V_{cc}=300V$, $V_{GE}=\pm 15V$, $R_g=33\Omega$, $T_j=25^\circ C$



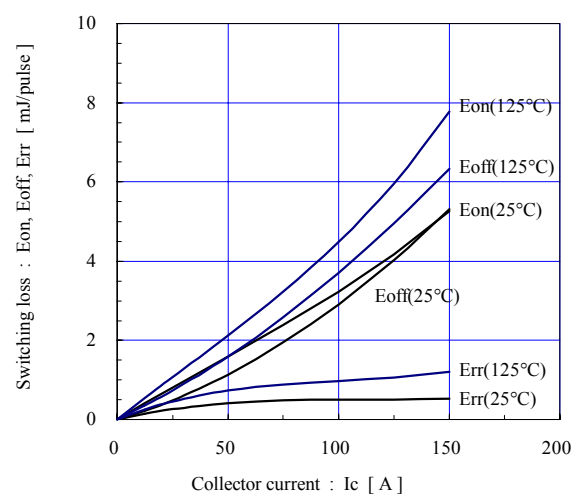
Switching time vs. Collector current (typ.)
 $V_{cc}=300V$, $V_{GE}=\pm 15V$, $R_g=33\Omega$, $T_j=125^\circ C$



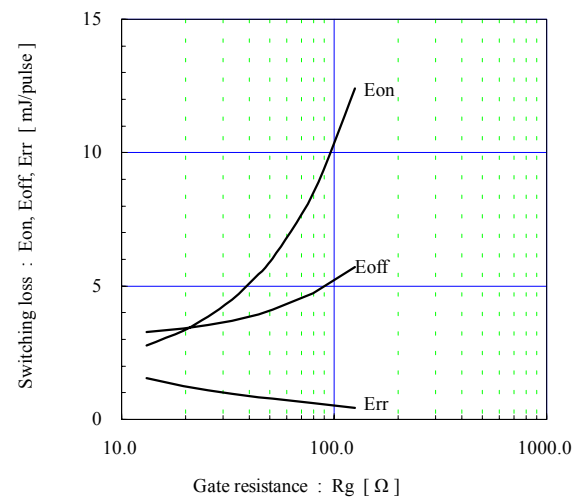
Switching time vs. Gate resistance (typ.)
 $V_{cc}=300V$, $I_c=100A$, $V_{GE}=\pm 15V$, $T_j=25^\circ C$



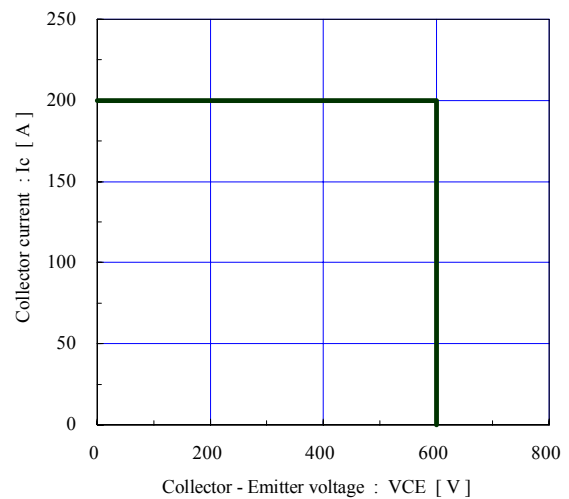
Switching loss vs. Collector current (typ.)
 $V_{cc}=300V$, $V_{GE}=\pm 15V$, $R_g=33\Omega$

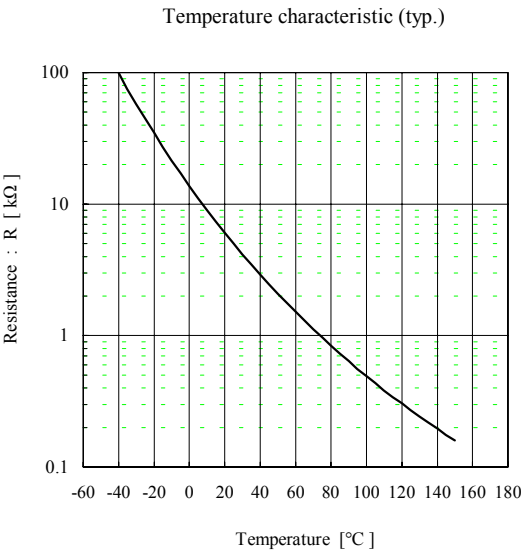
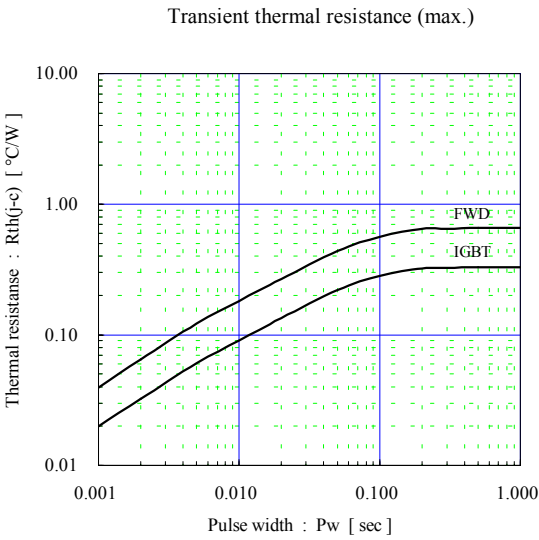
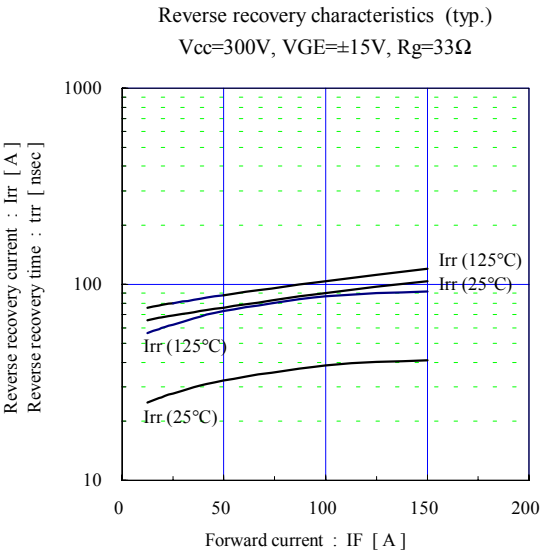
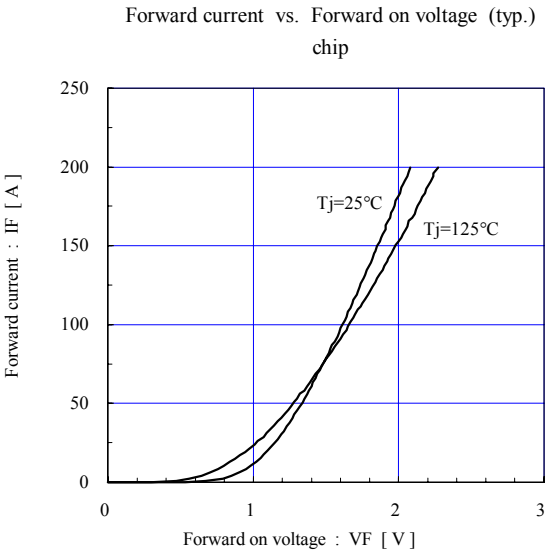


Switching loss vs. Gate resistance (typ.)
 $V_{cc}=300V$, $I_c=100A$, $V_{GE}=\pm 15V$, $T_j=125^\circ C$

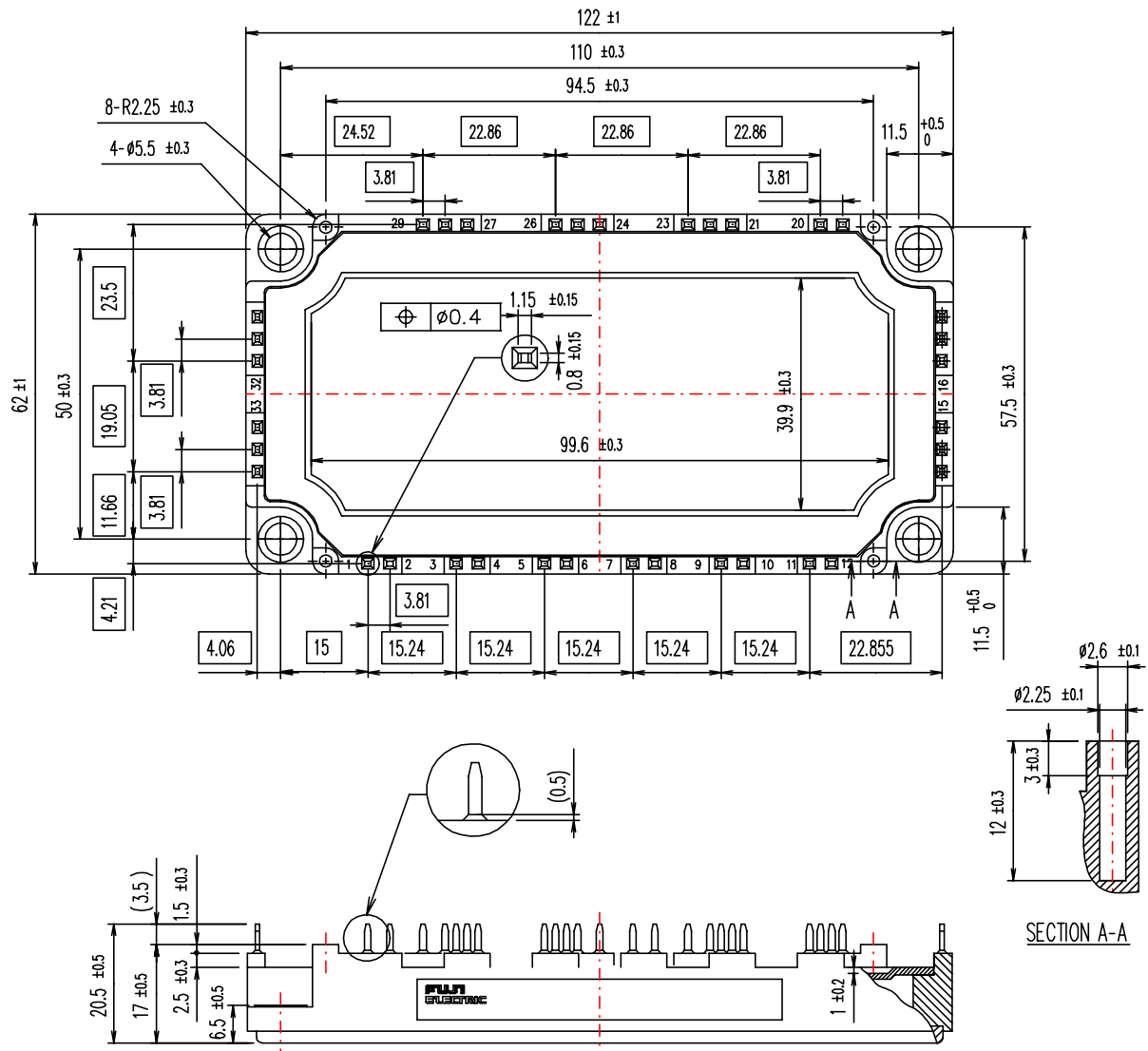


Reverse bias safe operating area (max.)
 $+V_{GE}=15V, -V_{GE} \leq 15V, R_g \geq 33\Omega, T_j \leq 125^\circ C$





■ Outline Drawings, mm



☐ shows theoretical dimension.

() shows reference dimension.